Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

Z86E30/E31/E40

Z8 4K OTP MICROCONTROLLER

FEATURES

Device	ROM (KB)	RAM* (Bytes)	I/O Lines	Speed (MHz)
Z86E30	4	237	24	16
Z86E31	2	125	24	16
Z86E40	4	236	32	16

Note: *General-Purpose

- Standard Temperature (V_{CC} = 3.5V to 5.5V)
- Extended Temperature (V_{CC} = 4.5V to 5.5V)
- Available Packages:
  28-Pin DIP/SOIC/PLCC OTP (Z86E30/31 only)
  40-Pin DIP OTP (Z86E40 only)
  44-Pin PLCC/LQFP OTP (Z86E40 only)
- Software Enabled Watch-Dog Timer (WDT)
- Push-Pull/Open-Drain Programmable on Port 0, Port 1, and Port 2
- 24/32 Input/Output Lines
- Auto Latches
- Auto Power-On Reset (POR)
- Programmable OTP Options:
  RC Oscillator
  EPROM Protect
  Auto Latch Disable
  Permanently Enabled WDT
  Crystal Oscillator Feedback Resistor Disable
  RAM Protect
- Low-Power Consumption: 60 mW
- Fast Instruction Pointer: 0.75 µs
- Two Standby Modes: STOP and HALT
- Digital Inputs CMOS Levels, Schmitt-Triggered
- Software Programmable Low EMI Mode
- Two Programmable 8-Bit Counter/Timers Each with a 6-Bit Programmable Prescaler
- Six Vectored, Priority Interrupts from Six Different Sources
- Two Comparators
- On-Chip Oscillator that Accepts a Crystal, Ceramic Resonator, LC, RC, or External Clock Drive

GENERAL DESCRIPTION

The Z86E30/E31/E40 8-Bit One-Time Programmable (OTP) Microcontrollers are members of Zilog's single-chip Z8® MCU family featuring enhanced wake-up circuitry, programmable Watch-Dog Timers, Low Noise EMI options, and easy hardware/software system expansion capability.

Four basic address spaces support a wide range of memory configurations. The designer has access to three additional control registers that allow easy access to register mapped peripheral and I/O circuits.

For applications demanding powerful I/O capabilities, the Z86E30/E31 have 24 pins, and the Z86E40 has 32 pins of dedicated input and output. These lines are grouped into four ports, eight lines per port, and are configurable under software control to provide timing, status signals, and parallel I/O with or without handshake, and address/data bus for interfacing external memory.

Notes: All signals with a preceding front slash, "/", are active Low. For example, B/$\overline{W}$ (WORD is active Low); $\overline{B}$/W (BYTE is active Low, only).

Power connections follow conventional descriptions below:

Connection	Circuit	Device
Power	V_{CC}	V_{DD}
Ground	GND	V_{SS}

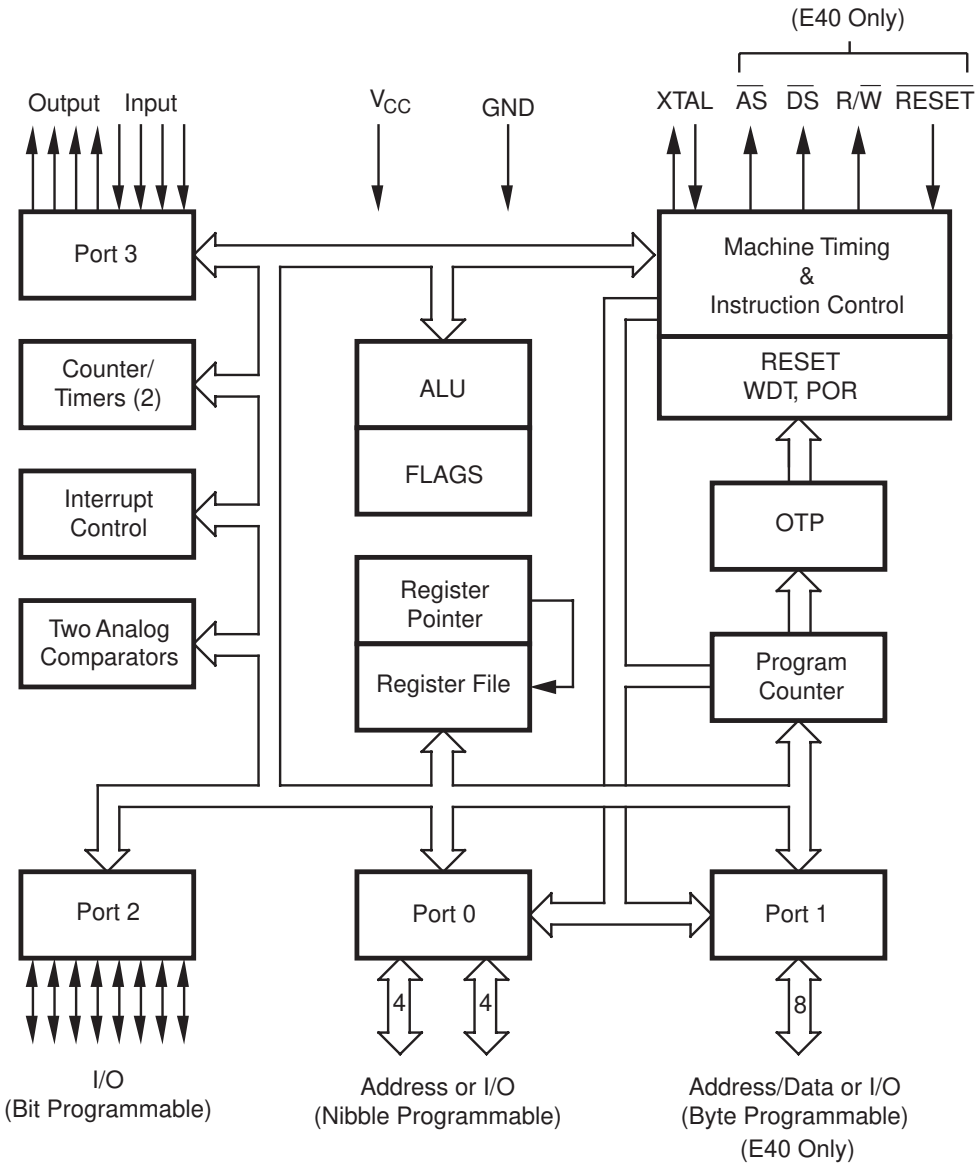

Figure 1. Z86E30/E31/E40 Functional Block Diagram

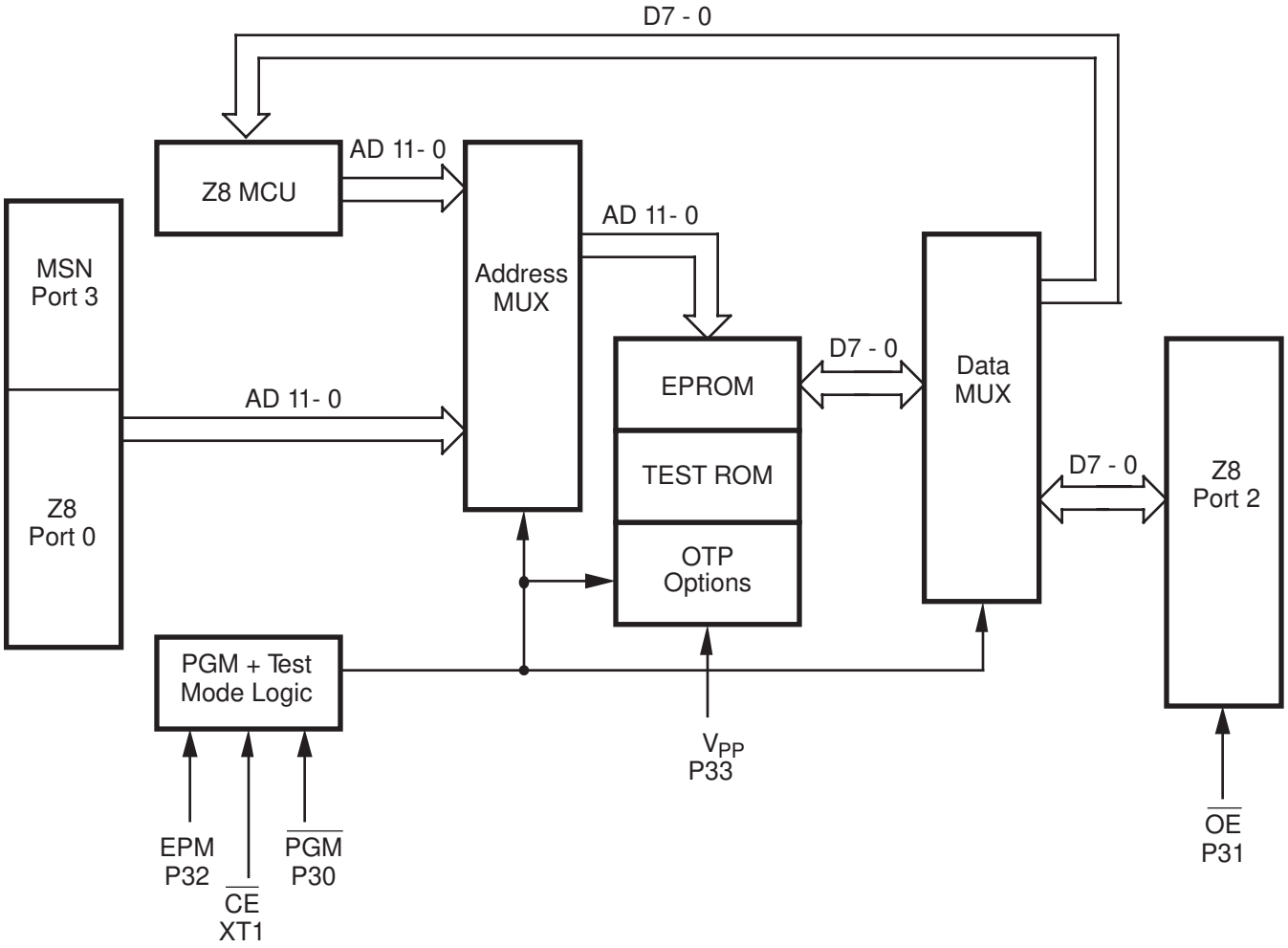

Figure 2. EPROM Programming Block Diagram

PIN IDENTIFICATION

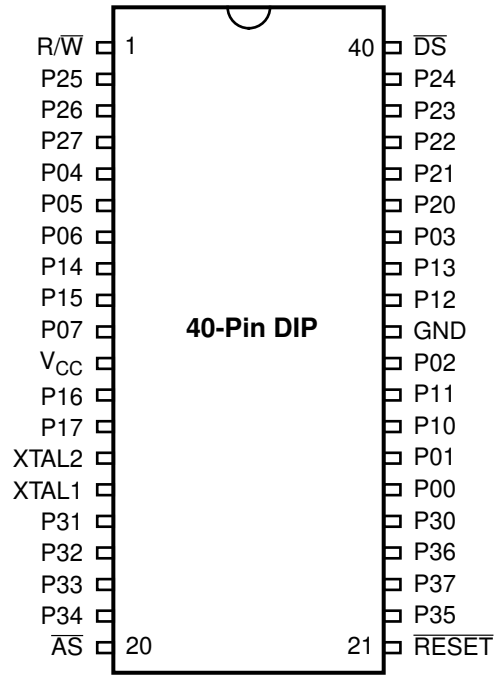

Figure 3. 40-Pin DIP Pin Configuration Standard Mode

Table 1. 40-Pin DIP Pin Identification Standard Mode

Pin #	Symbol	Function	Direction
1	R/$\overline{W}$	Read/Write	Output
2–4	P25–P27	Port 2, Pins 5,6,7	In/Output
5–7	P04–P06	Port 0, Pins 4,5,6	In/Output
8–9	P14–P15	Port 1, Pins 4,5	In/Output
10	P07	Port 0, Pin 7	In/Output
11	V_{CC}	Power Supply	
12–13	P16–P17	Port 1, Pins 6,7	In/Output
14	XTAL2	Crystal Oscillator	Output
15	XTAL1	Crystal Oscillator	Input
16–18	P31–P33	Port 3, Pins 1,2,3	Input
19	P34	Port 3, Pin 4	Output
20	$\overline{AS}$	Address Strobe	Output
21	$\overline{RESET}$	Reset	Input
22	P35	Port 3, Pin 5	Output
23	P37	Port 3, Pin 7	Output
24	P36	Port 3, Pin 6	Output
25	P30	Port 3, Pin 0	Input
26–27	P00–P01	Port 0, Pins 0,1	In/Output
28–29	P10–P11	Port 1, Pins 0,1	In/Output
30	P02	Port 0, Pin 2	In/Output
31	GND	Ground	
32–33	P12–P13	Port 1, Pins 2,3	In/Output
34	P03	Port 0, Pin 3	In/Output
35–39	P20–P24	Port 2, Pins 0,1,2,3,4	In/Output
40	$\overline{DS}$	Data Strobe	Output

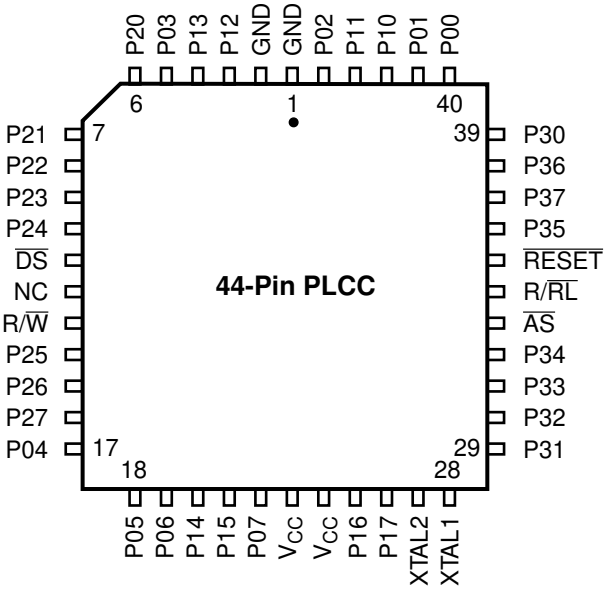

Figure 4. 44-Pin PLCC Pin Configuration
Standard Mode

Table 2. 44-Pin PLCC Pin Identification

Pin #	Symbol	Function	Direction
1–2	GND	Ground	
3–4	P12–P13	Port 1, Pins 2,3	In/Output
5	P03	Port 0, Pin 3	In/Output
6–10	P20–P24	Port 2, Pins 0,1,2,3,4	In/Output
11	$\overline{DS}$	Data Strobe	Output
12	NC	No Connection	
13	R/$\overline{W}$	Read/Write	Output
14–16	P25–P27	Port 2, Pins 5,6,7	In/Output
17–19	P04–P06	Port 0, Pins 4,5,6	In/Output
20–21	P14–P15	Port 1, Pins 4,5	In/Output
22	P07	Port 0, Pin 7	In/Output
23–24	V_{CC}	Power Supply	
25–26	P16–P17	Port 1, Pins 6,7	In/Output
27	XTAL2	Crystal Oscillator	Output
28	XTAL1	Crystal Oscillator	Input
29–31	P31–P33	Port 3, Pins 1,2,3	Input
32	P34	Port 3, Pin 4	Output

Table 2. 44-Pin PLCC Pin Identification

Pin #	Symbol	Function	Direction
33	$\overline{AS}$	Address Strobe	Output
34	R/$\overline{RL}$	ROM/ROMless select	Input
35	$\overline{RESET}$	Reset	Input
36	P35	Port 3, Pin 5	Output
37	P37	Port 3, Pin 7	Output
38	P36	Port 3, Pin 6	Output
39	P30	Port 3, Pin 0	Input
40–41	P00–P01	Port 0, Pins 0,1	In/Output
42–43	P10–P11	Port 1, Pins 0,1	In/Output
44	P02	Port 0, Pin 2	In/Output

PIN IDENTIFICATION (Continued)

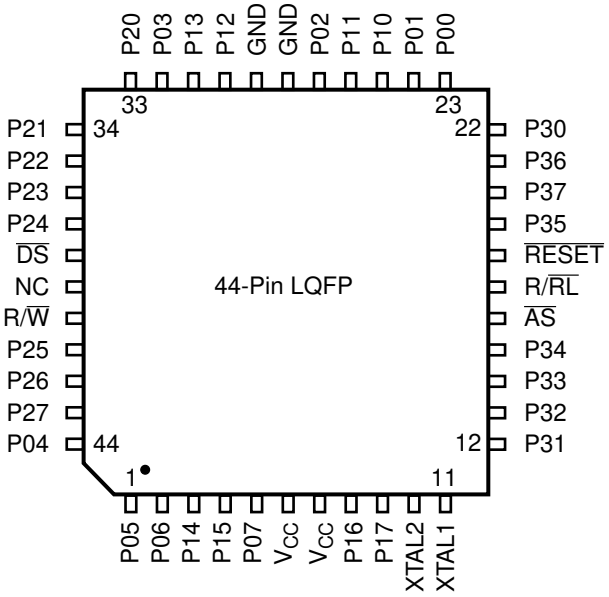

Figure 5. 44-Pin LQFP Pin Configuration
Standard Mode

Table 3. 44-Pin LQFP Pin Identification

Pin #	Symbol	Function	Direction
1–2	P05–P06	Port 0, Pins 5,6	In/Output
3–4	P14–P15	Port 1, Pins 4,5	In/Output
5	P07	Port 0, Pin 7	In/Output
6–7	V_{CC}	Power Supply	
8–9	P16–P17	Port 1, Pins 6,7	In/Output
10	XTAL2	Crystal Oscillator	Output
11	XTAL1	Crystal Oscillator	Input
12–14	P31–P33	Port 3, Pins 1,2,3	Input
15	P34	Port 3, Pin 4	Output
16	$\overline{AS}$	Address Strobe	Output
17	R/$\overline{RL}$	ROM/ROMless select	Input
18	$\overline{RESET}$	Reset	Input
19	P35	Port 3, Pin 5	Output
20	P37	Port 3, Pin 7	Output
21	P36	Port 3, Pin 6	Output
22	P30	Port 3, Pin 0	Input
23–24	P00–P01	Port 0, Pin 0,1	In/Output
25–26	P10–P11	Port 1, Pins 0,1	In/Output

Table 3. 44-Pin LQFP Pin Identification

Pin #	Symbol	Function	Direction
27	P02	Port 0, Pin 2	In/Output
28–29	GND	Ground	
30–31	P12–P13	Port 1, Pins 2,3	In/Output
32	P03	Port 0, Pin 3	In/Output
33–37	P20–4	Port 2, Pins 0,1,2,3,4	In/Output
38	$\overline{DS}$	Data Strobe	Output
39	NC	No Connection	
40	R/$\overline{W}$	Read/Write	Output
41–43	P25–P27	Port 2, Pins 5,6,7	In/Output
44	P04	Port 0, Pin 4	In/Output

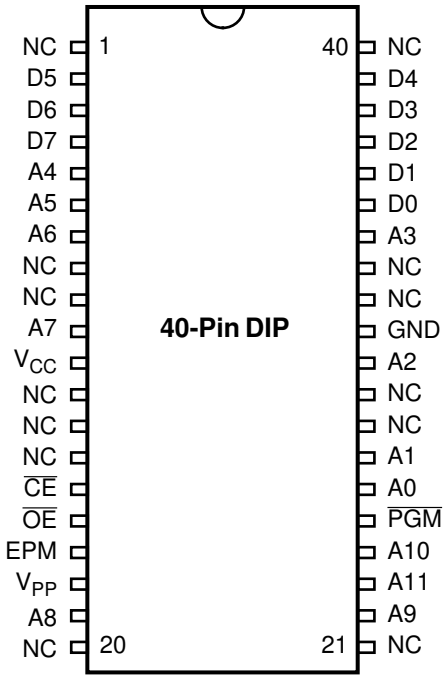

Figure 6. 40-Pin DIP Pin Configuration EPROM Mode

Table 4. 40-Pin DIP Package Pin Identification EPROM Mode

Pin #	Symbol	Function	Direction
1	NC	No Connection	
2–4	D5–D7	Data 5,6,7	In/Output
5–7	A4–A6	Address 4,5,6	Input
8–9	NC	No Connection	
10	A7	Address 7	Input
11	V_{CC}	Power Supply	
12–14	NC	No Connection	
15	$\overline{CE}$	Chip Select	Input
16	$\overline{OE}$	Output Enable	Input
17	EPM	EPROM Prog. Mode	Input
18	V_{PP}	Prog. Voltage	Input
19	A8	Address 8	Input
20–21	NC	No Connection	
22	A9	Address 9	Input
23	A11	Address 11	Input
24	A10	Address 10	Input
25	$\overline{PGM}$	Prog. Mode	Input
26–27	A0–A1	Address 0,1	Input
28–29	NC	No Connection	
30	A2	Address 2	Input
31	GND	Ground	
32–33	NC	No Connection	
34	A3	Address 3	Input
35–39	D0–D4	Data 0,1,2,3,4	In/Output
40	NC	No Connection	

PIN IDENTIFICATION (Continued)

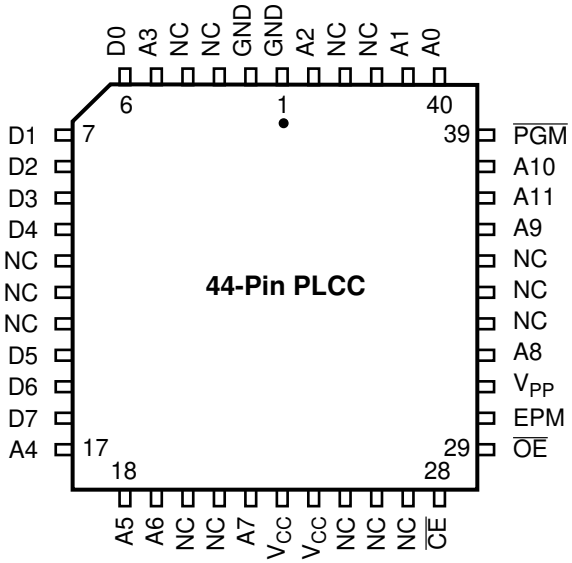

Figure 7. 44-Pin PLCC Pin Configuration EPROM Programming Mode

Table 5. 44-Pin PLCC Pin Configuration EPROM Programming Mode

Pin #	Symbol	Function	Direction
1–2	GND	Ground	
3–4	NC	No Connection	
5	A3	Address 3	Input
6–10	D0–D4	Data 0,1,2,3,4	In/Output
11–13	NC	No Connection	
14–16	D5–D7	Data 5,6,7	In/Output
17–19	A4–A6	Address 4,5,6	Input
20–21	NC	No Connection	
22	A7	Address 7	Input
23–24	V_{CC}	Power Supply	
25–27	NC	No Connection	
28	$\overline{CE}$	Chip Select	Input
29	$\overline{OE}$	Output Enable	Input
30	EPM	EPROM Prog. Mode	Input

Table 5. 44-Pin PLCC Pin Configuration EPROM Programming Mode

Pin #	Symbol	Function	Direction
31	V_{PP}	Prog. Voltage	Input
32	A8	Address 8	Input
33–35	NC	No Connection	
36	A9	Address 9	Input
37	A11	Address 11	Input
38	A10	Address 10	Input
39	$\overline{PGM}$	Prog. Mode	Input
40–41	A0,A1	Address 0,1	Input
42–43	NC	No Connection	
44	A2	Address 2	Input

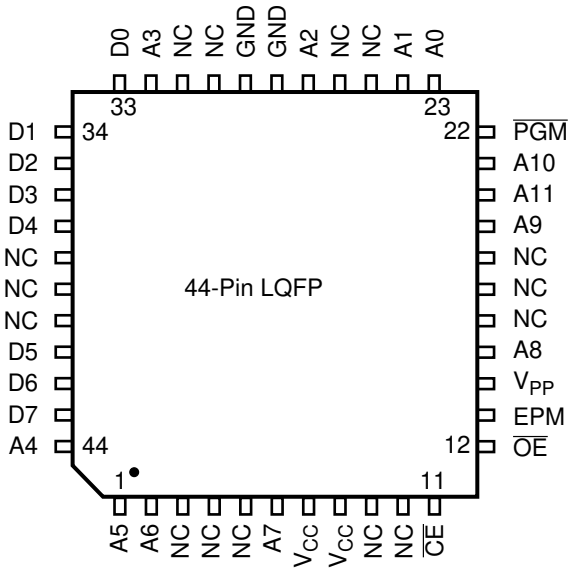

Figure 8. 44-Pin LQFP Pin Configuration
EPROM Programming Mode

Table 6. 44-Pin LQFP Pin Configuration
EPROM Programming Mode

Pin #	Symbol	Function	Direction
1–2	A5–A6	Address 5,6	Input
3–4	NC	No Connection	
5	A7	Address 7	Input
6–7	V_{CC}	Power Supply	
8–10	NC	No Connection	
11	$\overline{CE}$	Chip Select	Input
12	$\overline{OE}$	Output Enable	Input
13	EPM	EPROM Prog. Mode	Input
14	V_{PP}	Prog. Voltage	Input
15	A8	Address 8	Input
16–18	NC	No Connection	
19	A9	Address 9	Input
20	A11	Address 11	Input
21	A10	Address 10	Input
22	$\overline{PGM}$	Prog. Mode	Input

Table 6. 44-Pin LQFP Pin Configuration
EPROM Programming Mode

Pin #	Symbol	Function	Direction
23–24	A0,A1	Address 0,1	Input
25–26	NC	No Connection	
27	A2	Address 2	Input
28–29	GND	Ground	
30–31	NC	No Connection	
32	A3	Address 3	Input
33–37	D0–D4	Data 0,1,2,3,4	In/Output
38–40	NC	No Connection	
41–43	D5–D7	Data 5,6,7	In/Output
44	A4	Address 4	Input

PIN IDENTIFICATION (Continued)

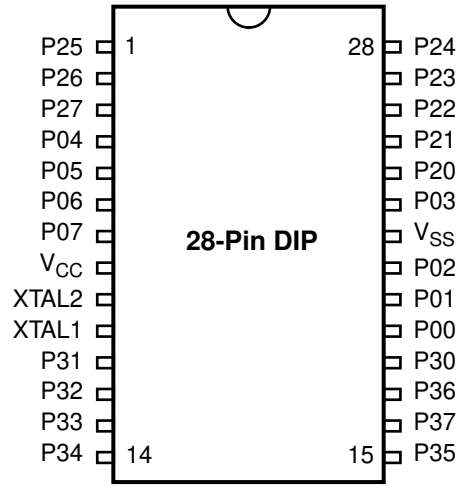

Figure 9. Standard Mode 28-Pin DIP/SOIC Pin Configuration

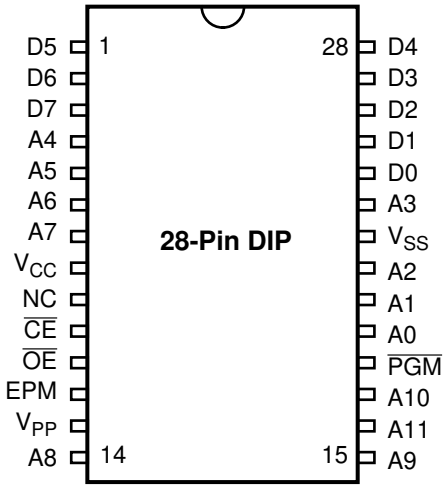

Figure 10. EPROM Programming Mode 28-Pin DIP/SOIC Pin Configuration

Table 7. 28-Pin DIP/SOIC/PLCC Pin Identification*

Pin #	Symbol	Function	Direction
1–3	P25–P27	Port 2, Pins 5,6,	In/Output
4–7	P04–P07	Port 0, Pins 4,5,6,7	In/Output
8	V_{CC}	Power Supply	
9	XTAL2	Crystal Oscillator	Output
10	XTAL1	Crystal Oscillator	Input
11–13	P31–P33	Port 3, Pins 1,2,3	Input
14–15	P34–P35	Port 3, Pins 4,5	Output
16	P37	Port 3, Pin 7	Output
17	P36	Port 3, Pin 6	Output
18	P30	Port 3, Pin 0	Input
19–21	P00–P02	Port 0, Pins 0,1,2	In/Output
22	V_{SS}	Ground	
23	P03	Port 0, Pin 3	In/Output
24–28	P20–P24	Port 2, Pins 0,1,2,3,4	In/Output

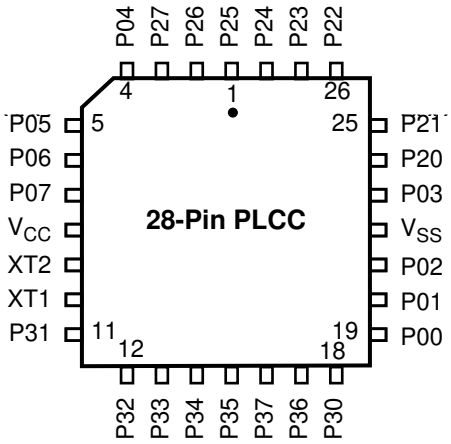

Figure 11. Standard Mode 28-Pin PLCC Pin Configuration

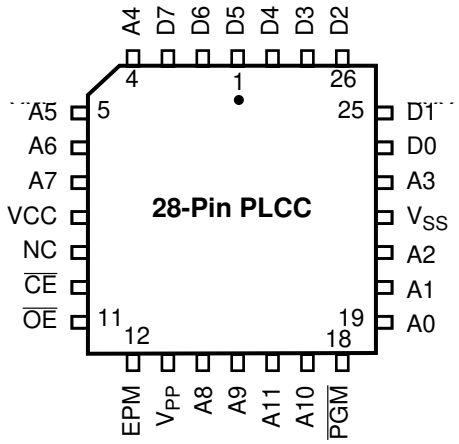

Figure 12. EPROM Programming Mode 28-Pin PLCC Pin Configuration

Table 8. 28-Pin EPROM Pin Identification

Pin #	Symbol	Function	Direction
1–3	D5–D7	Data 5,6,7	In/Output
4–7	A4–A7	Address 4,5,6,7	Input
8	V_{CC}	Power Supply	
9	NC	No connection	
10	$\overline{CE}$	Chip Select	Input
11	$\overline{OE}$	Output Enable	Input
12	EPM	EPROM Prog. Mode	Input
13	V_{PP}	Prog. Voltage	Input
14–15	A8–A9	Address 8,9	Input
16	A11	Address 11	Input
17	A10	Address 10	Input
18	$\overline{PGM}$	Prog. Mode	Input
19–21	A0–A2	Address 0,1,2	Input
22	V_{SS}	Ground	
23	A3	Address 3	Input
24–28	D0–D4	Data 0,1,2,3,4	In/Output

ABSOLUTE MAXIMUM RATINGS

Parameter	Min	Max	Units
Ambient Temperature under Bias	–40	+105	C
Storage Temperature	–65	+150	C
Voltage on any Pin with Respect to V_{SS} [Note 1]	–0.6	+7	V
Voltage on V_{DD} Pin with Respect to V_{SS}	–0.3	+7	V
Voltage on XTAL1 and $\overline{\text{RESET}}$ Pins with Respect to V_{SS} [Note 2]	–0.6	V_{DD}+1	V
Total Power Dissipation		1.21	W
Maximum Allowable Current out of V_{SS}		220	mA
Maximum Allowable Current into V_{DD}		180	mA
Maximum Allowable Current into an Input Pin [Note 3]	–600	+600	µA
Maximum Allowable Current into an Open-Drain Pin [Note 4]	–600	+600	µA
Maximum Allowable Output Current Sinked by Any I/O Pin		25	mA
Maximum Allowable Output Current Sourced by Any I/O Pin		25	mA
Maximum Allowable Output Current Sinked by $\overline{\text{RESET}}$ Pin		3 mA	

Notes:
1. This applies to all pins except XTAL pins and where otherwise noted.
2. There is no input protection diode from pin to V_{DD}.
3. This excludes XTAL pins.
4. Device pin is not at an output Low state.

Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at any condition above those indicated in the operational sections of these specifications is not implied. Exposure to absolute maximum rating conditions for an extended period may affect device reliability.

Total power dissipation should not exceed 1.2 W for the package. Power dissipation is calculated as follows:

Total Power Dissipation = V_{DD} x [I_{DD} – (sum of I_{OH})]
+ sum of [(V_{DD} – V_{OH}) x I_{OH}]
+ sum of (V_{0L} x I_{0L})

STANDARD TEST CONDITIONS

The characteristics listed below apply for standard test conditions as noted. All voltages are referenced to Ground. Positive current flows into the referenced pin (Test Load).

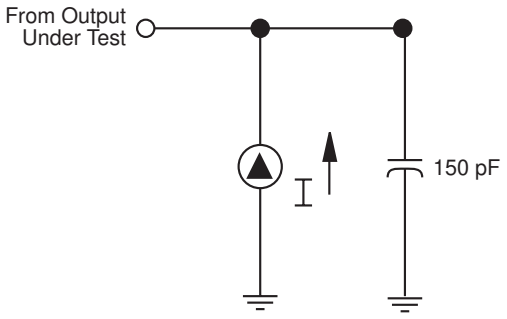

Figure 13. Test Load Diagram

CAPACITANCE

T_A = 25°C, V_{CC} = GND = 0V, f = 1.0 MHz; unmeasured pins returned to GND.

Parameter	Min	Max
Input capacitance	0	12 pF
Output capacitance	0	12 pF
I/O capacitance	0	12 pF

DC ELECTRICAL CHARACTERISTICS

			T_A= 0 °C to +70 °C					
Sym	Parameter	V_{CC} Note [3]	Min	Max	Typical @ 25°C	Units	Conditions	Notes
V_{CH}	Clock Input High Voltage	3.5V 5.5V	0.7 V_{CC} 0.7 V_{CC}	V_{CC}+0.3 V_{CC}+0.3	1.8 2.5	V V	Driven by External Clock Generator	
V_{CL}	Clock Input Low Voltage	3.5V 4.5V	GND -0.3 GND -0.3	0.2 V_{CC} 0.2 V_{CC}	0.9 1.5	V V	Driven by External Clock Generator	
V_{IH}	Input High Voltage	3.5V 5.5V	0.7 V_{CC} 0.7 V_{CC}	V_{CC}+0.3 V_{CC}+0.3	2.5 2.5	V V		
V_{IL}	Input Low Voltage	3.5V 5.5V	GND -0.3 GND -0.3	0.2 V_{CC} 0.2 V_{CC}	1.5 1.5	V V		
V_{OH}	Output High Voltage Low EMI Mode	3.5V 5.5V	V_{CC} -0.4 V_{CC} -0.4		3.3 4.8	V V	I_{OH} = – 0.5 mA	
V_{OH1}	Output High Voltage	3.5V 5.5V	V_{CC} -0.4 V_{CC} -0.4		3.3 4.8	V V	I_{OH} = -2.0 mA I_{OH} = -2.0 mA	
V_{OL}	Output Low Voltage Low EMI Mode	3.5V 4.5V		0.4 0.4	0.2 0.2	V V	I_{OL} = 1.0 mA I_{OL} = 1.0 mA	
V_{OL1}	Output Low Voltage	3.5V 4.5V		0.4 0.4	0.1 0.1	V V	I_{OL} = + 4.0 mA I_{OL} = + 4.0 mA	8 8
V_{OL2}	Output Low Voltage	3.5V 4.5V		1.2 1.2	0.5 0.5	V V	I_{OL} = + 12 mA I_{OL} = + 12 mA	8 8
V_{RH}	Reset Input High Voltage	3.5V 5.5V	.8 V_{CC} .8 V_{CC}	V_{CC} V_{CC}	1.7 2.1	V V		
V_{RL}	Reset Input Low Voltage	3.5V 5.5V	GND -0.3 GND -0.3	0.2 V_{CC} 0.2 V_{CC}	1.3 1.7	V V		13
V_{OLR}	Reset Output Low Voltage	3.5V 5.5V		0.6 0.6	0.3 0.2	V V	I_{OL} = 1.0 mA I_{OL} = 1.0 mA	
V_{OFFSET}	Comparator Input Offset Voltage	3.5V 4.5V		25 25	10 10	mV mV		
V_{ICR}	Input Common Mode Voltage Range	3.5V 5.5V	0 0	V_{CC} -1.0V V_{CC} -1.0V		V V		10 10
I_{IL}	Input Leakage	3.5V 4.5V	-1 -1	2 2	0.032 0.032	µA µA	V_{IN} = 0V, V_{CC} V_{IN} = 0V, V_{CC}	
I_{OL}	Output Leakage	3.5V 4.5V	-1 -1	2 2	0.032 0.032	µA µA	V_{IN} = 0V, V_{CC} V_{IN} = 0V, V_{CC}	
I_{IR}	Reset Input Current	3.5V 4.5V	-20 -20	-130 -180	-65 -112	µA µA		

DC ELECTRICAL CHARACTERISTICS (Continued)

			T_A= 0 °C to +70 °C					
Sym	Parameter	V_{CC} Note [3]	Min	Max	Typical @ 25°C	Units	Conditions	Notes
I_{CC}	Supply Current	3.5V		20	7	mA	@ 16 MHz	4,5
		5.5V		25	20	mA	@ 16 MHz	4,5
I_{CC1}	Standby Current Halt Mode	3.5V		8	3.7	mA	V_{IN} = 0V, V_{CC}	4,5
		5.5V		8	3.7	mA	@ 16 MHz	4,5
		3.5V		7.0	2.9	mA	Clock Divide by	4,5
		5.5V		7.0	2.9	mA	16 @ 16 MHz	4,5
I_{CC2}	Standby Current Stop Mode	3.5V		10	2	µA	V_{IN} = 0V, V_{CC}	6,11
		5.5V		10	3	µA	V_{IN} = 0V, V_{CC}	6,11
		3.5V		800	600	µA	V_{IN} = 0V, V_{CC}	6,11,14
		5.5V		800	600	µA	V_{IN} = 0V, V_{CC}	6,11,14
I_{ALL}	Auto Latch Low Current	3.5V	0.7	8	2.4	µA	0V <V_{IN}<V_{CC}	9
		5.5V	1.4	15	4.7	µA	0V <V_{IN}<V_{CC}	9
I_{ALH}	Auto Latch High Current	3.5V	-0.6	-5	-1.8	µA	0V<V_{IN}<V_{CC}	9
		5.5V	-1	-8	-3.8	µA	0V<V_{IN}<V_{CC}	9
T_{POR}	Power On Reset	3.5V	3.0	24	7	ms		
		5.5V	2.0	13	4	ms		
V_{LV}	Auto Reset Voltage		2.3	3.1	2.9	V		1,7

Notes:

1. Device does function down to the Auto Reset voltage.
2. GND=0V
3. The V_{CC} voltage specification of 5.5V guarantees 5.0V ± 0.5V and the V_{CC} voltage specification of 3.5V guarantees only 3.5V.
4. All outputs unloaded, I/O pins floating, inputs at rail.
5. CL1= CL2 = 22 pF
6. Same as note [4] except inputs at $V_{CC.}$
7. Max. temperature is 70°C.
8. STD Mode (not Low EMI Mode)
9. Auto Latch (mask option) selected
10. For analog comparator inputs when analog comparators are enabled.
11. Clock must be forced Low, when XTAL1 is clock driven and XTAL2 is floating.
12. Typicals are at V_{CC} = 5.0V and V_{CC} = 3.5V
13. Z86E40 only
14. WDT running

Sym	Parameter	V_{CC} Note [3]	Min	Max	Typical @ 25°C	Units	Conditions	Notes
			T_A=–40 °C to +105 °C					
V_{CH}	Clock Input High Voltage	4.5V	0.7 V_{CC}	V_{CC}+0.3	2.5	V	Driven by External	
		5.5V	0.7 V_{CC}	V_{CC}+0.3	2.5	V	Clock Generator	
V_{CL}	Clock Input Low Voltage	4.5V	GND-0.3	0.2 V_{CC}	1.5	V	Driven by External	
		5.5V	GND-0.3	0.2 V_{CC}	1.5	V	Clock Generator	
V_{IH}	Input High Voltage	4.5V	0.7 V_{CC}	V_{CC}+0.3	2.5	V		
		5.5V	0.7 V_{CC}	V_{CC}+0.3	2.5	V		
V_{IL}	Input Low Voltage	4.5V	GND-0.3	0.2 V_{CC}	1.5	V		
		5.5V	GND-0.3	0.2 V_{CC}	1.5	V		
V_{OH}	Output High Voltage Low EMI Mode	4.5V	V_{CC} -0.4		4.8	V	I_{OH} = – 0.5 mA	8
		5.5V	V_{CC} -0.4		4.8	V	I_{OH} = – 0.5 mA	8
V_{OH1}	Output High Voltage	4.5V	V_{CC} -0.4		4.8	V	I_{OH} = -2.0 mA	8
		4.5V	V_{CC} -0.4		4.8	V	I_{OH} = -2.0 mA	8
V_{OL}	Output Low Voltage Low EMI Mode	4.5V		0.4	0.2	V	I_{OL} = 1.0 mA	
		5.5V		0.4	0.2	V	I_{OL} = 1.0 mA	
V_{OL1}	Output Low Voltage	4.5V		0.4	0.1	V	I_{OL} = + 4.0 mA	8
		5.5V		0.4	0.1	V	I_{OL} = +4.0 mA	8
V_{OL2}	Output Low Voltage	4.5V		1.2	0.5	V	I_{OL} = + 12 mA	8
		5.5V		1.2	0.5	V	I_{OL} = + 12 mA	8
V_{RH}	Reset Input High Voltage	3.5V	.8 V_{CC}	V_{CC}	1.7	V		13
		5.5V	.8 V_{CC}	V_{CC}	2.1	V		13
V_{OLR}	Reset Output Low Voltage	3.5V		0.6	0.3	V	I_{OL} = 1.0 mA	13
		5.5V		0.6	0.2	V	I_{OL} = 1.0 mA	13
V_{OFFSET}	Comparator Input Offset Voltage	4.5V		25	10	mV		
		5.5V		25	10	mV		
V_{ICR}	Input Common Mode Voltage Range	4.5V	0	V_{CC}-1.5V		V		10
		5.5V	0	V_{CC}-1.5V		V		10
I_{IL}	Input Leakage	4.5V	-1	2	<1	µA	V_{IN} = 0V, V_{CC}	
		5.5V	-1	2	<1	µA	V_{IN} = 0V, V_{CC}	
I_{OL}	Output Leakage	4.5V	-1	2	<1	µA	V_{IN} = 0V, V_{CC}	
		5.5V	-1	2	<1	µA	V_{IN} = 0V, V_{CC}	
I_{IR}	Reset Input Current	4.5V	-18	-180	-112	µA		
		5.5V	-18	-180	-112	µA		
I_{CC}	Supply Current	4.5V		25	20	mA	@ 16 MHz	4,5
		5.5V		25	20	mA	@ 16 MHz	4,5
I_{CC1}	Standby Current Halt Mode	4.5V		8	3.7	mA	V_{IN} = 0V, V_{CC} @ 16 MHz	4,5
		5.5V		8	3.7	mA	V_{IN} = 0V, V_{CC} @ 16 MHz	4,5
I_{CC2}	Standby Current (Stop Mode)	4.5V		10	2	µA	V_{IN} = 0V, V_{CC}	6,11,14
		5.5V		10	3	µA	V_{IN} = 0V, V_{CC}	6,11,14
I_{ALL}	Auto Latch Low Current	4.5V	1.4	20	4.7	µA	0V < V_{IN} < V_{CC}	9
		5.5V	1.4	20	4.7	µA	0V < V_{IN} < V_{CC}	9

DC ELECTRICAL CHARACTERISTICS (Continued)

			T_A=–40 °C to +105 °C					
Sym	Parameter	V_{CC} Note [3]	Min	Max	Typical @ 25°C	Units	Conditions	Notes
I_{ALH}	Auto Latch High	4.5V	-1.0	-10	-3.8	µA	$0V < V_{IN} < V_{CC}$	9
	Current	5.5V	-1.0	-10	-3.8	µA	$0V < V_{IN} < V_{CC}$	9
T_{POR}	Power On Reset	4.5V	2.0	14	4	mS		
		5.5V	2.0	14	4	mS		
V_{LV}	Auto Reset Voltage		2.0	3.3	2.9	V		1

1. Device does function down to the Auto Reset voltage.
2. GND=0V
3. The V_{CC} voltage specification of 5.5V guarantees 5.0V ± 0.5V.
4. All outputs unloaded, I/O pins floating, inputs at rail.
5. CL1= CL2 = 22 pF
6. Same as note [4] except inputs at V_{CC}.
7. Maximum temperature is 70°C
8. STD Mode (not Low EMI Mode)
9. Auto Latch (mask option) selected
10. For analog comparator inputs when analog comparators are enabled.
11. Clock must be forced Low, when XTAL1 is clock driven and XTAL2 is floating.
12. Typicals are at V_{CC} = 5.0V
13. Z86E40 only
14. WDT is not running.

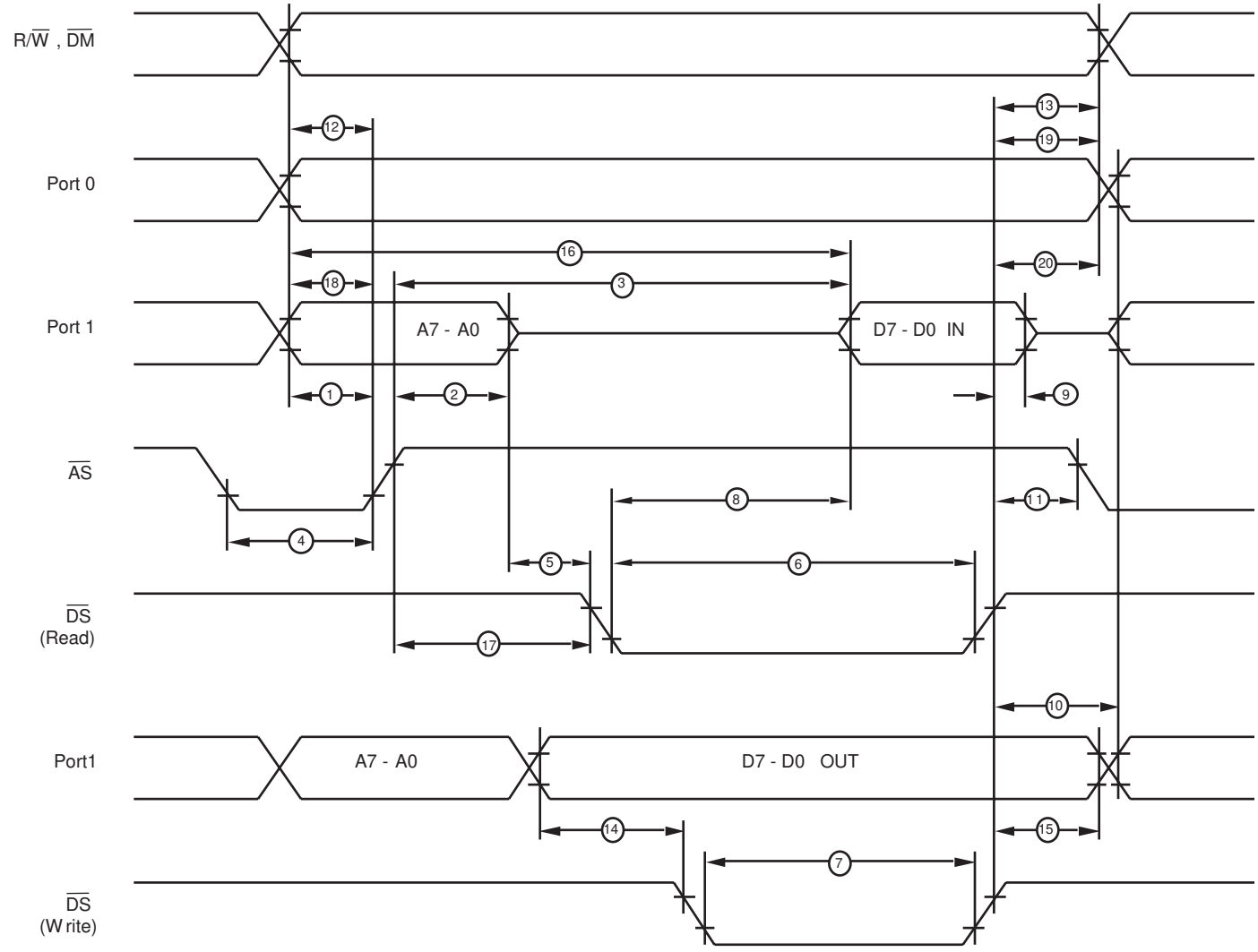

Figure 14. External I/O or Memory Read/Write Timing
Z86E40 Only

DC ELECTRICAL CHARACTERISTICS (Continued)

				T_A = 0°C to 70°C 16 MHz			
No	Symbol	Parameter	Note [3] V_{CC}	Min	Max	Units	Notes
1	TdA(AS)	Address Valid to $\overline{AS}$ Rise Delay	3.5V 5.5V	25 25		ns ns	2
2	TdAS(A)	$\overline{AS}$ Rise to Address Float Delay	3.5V 5.5V	35 35		ns ns	2
3	TdAS(DR)	$\overline{AS}$ Rise to Read Data Req'd Valid	3.5V 5.5V		180 180	ns ns	1,2
4	TwAS	$\overline{AS}$ Low Width	3.5V 5.5V	40 40		ns ns	2
5	TdAS(DS)	Address Float to $\overline{DS}$ Fall	3.5V 5.5V	0 0		ns ns	
6	TwDSR	$\overline{DS}$ (Read) Low Width	3.5V 5.5V	135 135		ns ns	1,2
7	TwDSW	$\overline{DS}$ (Write) Low Width	3.5V 5.5V	80 80		ns ns	1,2
8	TdDSR(DR)	$\overline{DS}$ Fall to Read Data Req'd Valid	3.5V 5.5V		75 75	ns ns	1,2
9	ThDR(DS)	Read Data to $\overline{DS}$ Rise Hold Time	3.5V 5.5V	0 0		ns ns	2
10	TdDS(A)	$\overline{DS}$ Rise to Address Active Delay	3.5V 5.5V	50 50		ns ns	2
11	TdDS(AS)	$\overline{DS}$ Rise to $\overline{AS}$ Fall Delay	3.5V 5.5V	35 35		ns ns	2
12	TdR/W(AS)	R/$\overline{W}$ Valid to $\overline{AS}$ Rise Delay	3.5V 5.5V	25 25		ns ns	2
13	TdDS(R/W)	$\overline{DS}$ Rise to R/$\overline{W}$ Not Valid	3.5V 5.5V	35 35		ns ns	2
14	TdDW(DSW)	Write Data Valid to $\overline{DS}$ Fall (Write) Delay	3.5V 5.5V	55 55	25 25	ns ns	2
15	TdDS(DW)	$\overline{DS}$ Rise to Write Data Not Valid Delay	3.5V 5.5V	35 35		ns ns	2
16	TdA(DR)	Address Valid to Read Data Req'd Valid	3.5V 5.5V		230 230	ns ns	1,2
17	TdAS(DS)	$\overline{AS}$ Rise to $\overline{DS}$ Fall Delay	3.5V 5.5V	45 45		ns ns	2
18	TdDM(AS)	$\overline{DM}$ Valid to $\overline{AS}$ Fall Delay	3.5V 5.5V	30 30		ns ns	2
20	ThDS(AS)	$\overline{DS}$ Valid to Address Valid Hold Time	3.5V 5.5V	35 35		ns ns	

Notes:

1. When using extended memory timing, add 2 TpC.
2. Timing numbers given are for minimum TpC.
3. The V_{CC} voltage specification of 5.5V guarantees 5.0V ±0.5V and the V_{CC} voltage specification of 3.5V guarantees only 3.5V

Standard Test Load

All timing references use 0.7 V_{CC} for a logic 1 and 0.2 V_{CC} for a logic 0.

For Standard Mode (not Low-EMI Mode for outputs) with SMR D1 = 0, D0 = 0.

			T_A = -40°C to 105°C 16 MHz				
No	Symbol	Parameter	Note [3] V_{CC}	Min	Max	Units	Notes
1	TdA(AS)	Address Valid to $\overline{AS}$ Rise Delay	4.5V 5.5V	25 25		ns ns	2
2	TdAS(A)	$\overline{AS}$ Rise to Address Float Delay	4.5V 5.5V	35 35		ns ns	2
3	TdAS(DR)	$\overline{AS}$ Rise to Read Data Req'd Valid	4.5V 5.5V		180 180	ns ns	1,2
4	TwAS	$\overline{AS}$ Low Width	4.5V 5.5V	40 40		ns ns	2
5	TdAS(DS)	Address Float to $\overline{DS}$ Fall	4.5V 5.5V	0 0		ns ns	
6	TwDSR	$\overline{DS}$ (Read) Low Width	4.5V 5.5V	135 135		ns ns	1,2
7	TwDSW	$\overline{DS}$ (Write) Low Width	4.5V 5.5V	80 80		ns ns	1,2
8	TdDSR(DR)	$\overline{DS}$ Fall to Read Data Req'd Valid	4.5V 5.5V		75 75	ns ns	1,2
9	ThDR(DS)	Read Data to $\overline{DS}$ Rise Hold Time	4.5V 5.5V	0 0		ns ns	2
10	TdDS(A)	$\overline{DS}$ Rise to Address Active Delay	4.5V 5.5V	50 50		ns ns	2
11	TdDS(AS)	$\overline{DS}$ Rise to $\overline{AS}$ Fall Delay	4.5V 5.5V	35 35		ns ns	2
12	TdR/W(AS)	R/$\overline{W}$ Valid to $\overline{AS}$ Rise Delay	4.5V 5.5V	25 25		ns ns	2
13	TdDS(R/W)	$\overline{DS}$ Rise to R/$\overline{W}$ Not Valid	4.5V 5.5V	35 35		ns ns	2
14	TdDW(DSW)	Write Data Valid to $\overline{DS}$ Fall (Write) Delay	4.5V 5.5V	55 55	25 25	ns ns	2
15	TdDS(DW)	$\overline{DS}$ Rise to Write Data Not Valid Delay	4.5V 5.5V	35 35		ns ns	2
16	TdA(DR)	Address Valid to Read Data Req'd Valid	4.5V 5.5V		230 230	ns ns	1,2
17	TdAS(DS)	$\overline{AS}$ Rise to $\overline{DS}$ Fall Delay	4.5V 5.5V	45 45		ns ns	2
18	TdDM(AS)	/DM Valid to $\overline{AS}$ Fall Delay	4.5V 5.5V	30 30		ns ns	2
20	ThDS(AS)	$\overline{DS}$ Valid to Address Valid Hold Time	4.5V 5.5V	35 35		ns ns	

Notes:

1. When using extended memory timing, add 2 TpC.
2. Timing numbers given are for minimum TpC.
3. The V_{CC} voltage specification of 5.5V guarantees 5.0V ±0.5V and the V_{CC} voltage specification of 3.5V guarantees only 3.5V

Standard Test Load

All timing references use 0.7 V_{CC} for a logic 1 and 0.2 V_{CC} for a logic 0.

For Standard Mode (not Low-EMI Mode for outputs) with SMR, D1 = 0, D0 = 0.

DC ELECTRICAL CHARACTERISTICS (Continued)

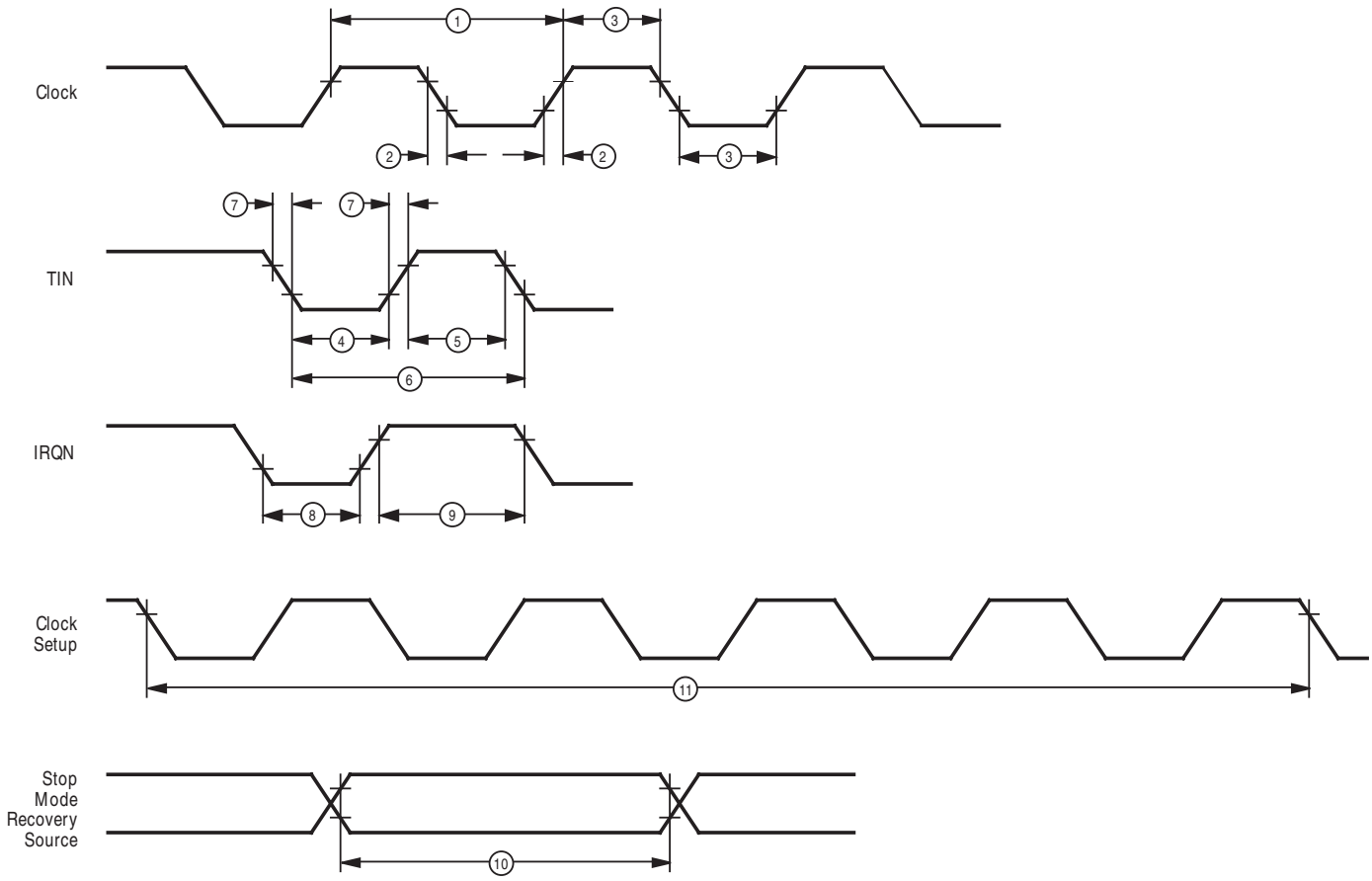

Figure 15. Additional Timing Diagram

Additional Timing Table (Divide-By-One Mode)

				T_A = 0 °C to +70 °C		T_A = -40 °C to +105 °C			
				4 MHz		4 MHz			
No	Symbol	Parameter	V_{CC} Note [6]	Min	Max	Min	Max	Units	Notes
1	TpC	Input Clock Period	3.5V	250	DC	250	DC	ns	1,7,8
			5.5V	250	DC	250	DC	ns	1,7,8
2	TrC,TfC	Clock Input Rise &	3.5V		25		25	ns	1,7,8
		Fall Times	5.5V		25		25	ns	1,7,8
3	TwC	Input Clock Width	3.5V	100		100		ns	1,7,8
			5.5V	100		100		ns	1,7,8
4	TwTinL	Timer Input Low	3.5V	100		100		ns	1,7,8
		Width	5.5V	70		70		ns	1,7,8
5	TwTinH	Timer Input High	3.5V	5TpC		5TpC			1,7,8
		Width	5.5V	5TpC		5TpC			1,7,8
6	TpTin	Timer Input Period	3.5V	8TpC		8TpC			1,7,8
			5.5V	8TpC		8TpC			1,7,8
7	TrTin, TfTin	Timer Input Rise	3.5V		100		100	ns	1,7,8
		& Fall Timer	5.5V		100		100	ns	1,7,8
8A	TwIL	Int. Request Low	3.5V	100		100		ns	1,2,7,8
		Time	5.5V	70		70		ns	1,2,7,8
8B	TwIL	Int. Request Low	3.5V	5TpC		5TpC			1,3,7,8
		Time	5.5V	5TpC		5TpC			1,3,7,8
9	TwIH	Int. Request Input	3.5V	5TpC		5TpC			1,2,7,8
		High Time	5.5V	5TpC		5TpC			1,2,7,8
10	Twsm	STOP Mode	3.5V	12		12		ns	4,8
		Recovery Width	5.5V	12		12		ns	4,8
		Spec							
11	Tost	Oscillator Startup	3.5V		5TpC		5TpC		4,8,9
		Time	5.5V		5TpC				

Notes:

1. Timing Reference uses 0.7 V_{CC} for a logic 1 and 0.2 V_{CC} for a logic 0.
2. Interrupt request via Port 3 (P31–P33).
3. Interrupt request via Port 3 (P30).
4. SMR-D5 = 1, POR STOP Mode Delay is on.
5. Reg. WDTMR.
6. The V_{CC} voltage specification of 5.5V guarantees 5.0V ± 0.5V and the V_{CC} voltage specification of 3.5V guarantees 3.5V only.
7. SMR D1 = 0.
8. Maximum frequency for internal system clock is 4 MHz when using XTAL divide-by-one mode.
9. For RC and LC oscillator, and for oscillator driven by clock driver.

DC ELECTRICAL CHARACTERISTICS (Continued)

Handshake Timing Diagrams

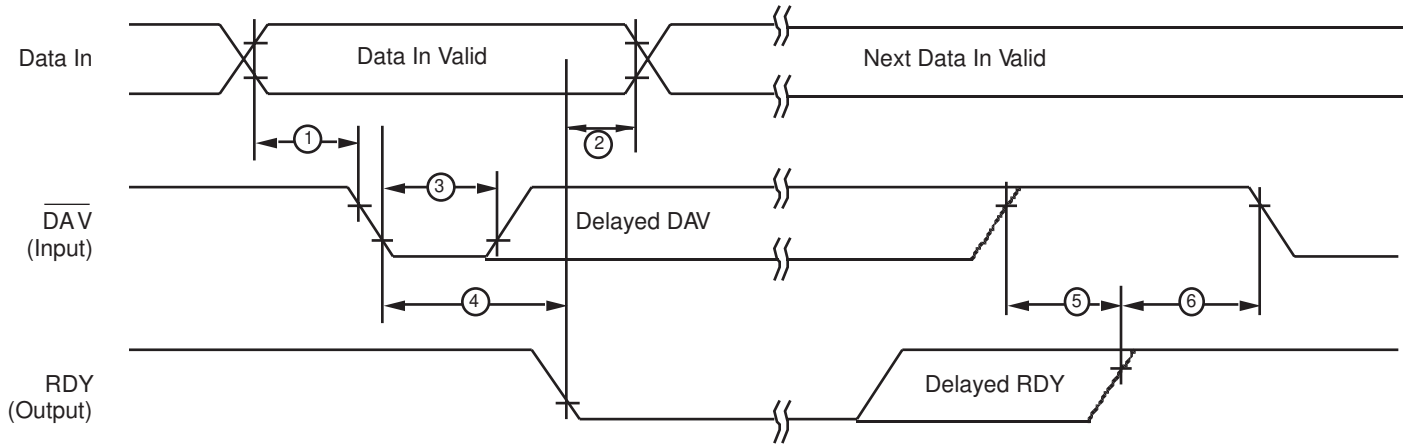

Figure 16. Input Handshake Timing

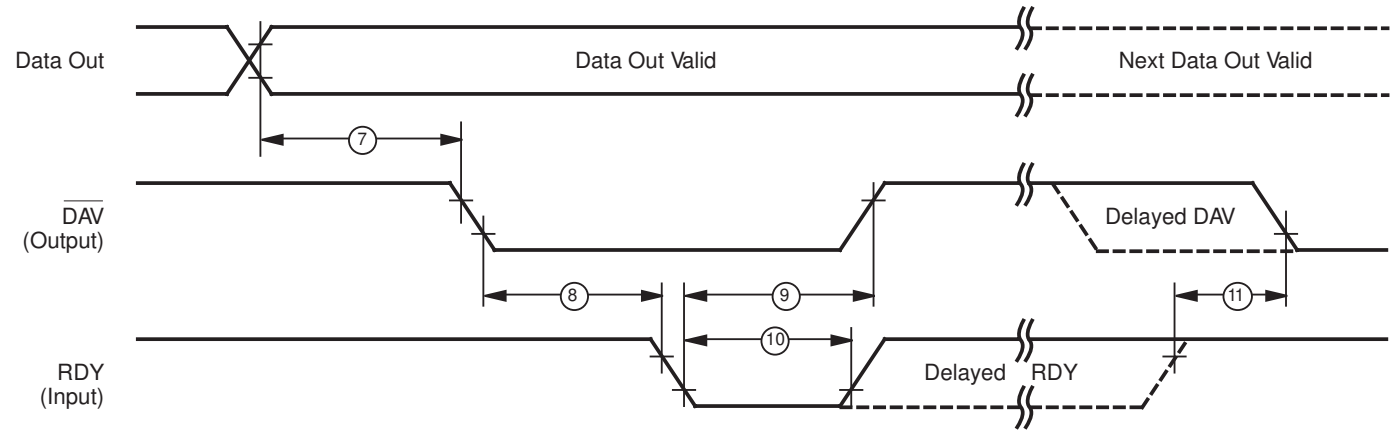

Figure 17. Output Handshake Timing

Additional Timing Table

			T_A = -40 °C to +105 °C 16 MHz					
No	Symbol	Parameter	V_{CC} Note [6]	Min	Max	Units	Conditions	Notes
1	TpC	Input Clock Period	3.5V	62.5	DC	ns		1,7,8
			5.5V	62.5	DC	ns		1,7,8
2	TrC,TfC	Clock Input Rise & Fall Times	3.5V		15	ns		1,7,8
			5.5V		15	ns		1,7,8
3	TwC	Input Clock Width	3.5V	31		ns		1,7,8
			5.5V	31		ns		1,7,8
4	TwTinL	Timer Input Low Width	3.5V	70		ns		1,7,8
			5.5V	70		ns		1,7,8
5	TwTinH	Timer Input High Width	3.5V	5TpC				1,7,8
			5.5V	5TpC				1,7,8
6	TpTin	Timer Input Period	3.5V	8TpC				1,7,8
			5.5V	8TpC				1,7,8
7	TrTin, TfTin	Timer Input Rise & Fall Timer	3.5V		100	ns		1,7,8
			5.5V		100	ns		1,7,8
8A	TwIL	Int. Request Low Time	3.5V	70		ns		1,2,7,8
			5.5V	70		ns		1,2,7,8
8B	TwIL	Int. Request Low Time	3.5V	5TpC				1,3,7,8
			5.5V	5TpC				1,3,7,8
9	TwIH	Int. Request Input High Time	3.5V	5TpC				1,2,7,8
			5.5V					
10	Twsm	STOP Mode Recovery Width Spec	3.5V	12		ns		4,8
			5.5V	12		ns		4,8
11	Tost	Oscillator Startup Time	3.5V		5TpC			4,8
			5.5V		5TpC			4,8
12	Twdt	Watch-Dog Timer Delay Time Before Timeout	3.5V	10		ms	D0 = 0	5,11
			5.5V	5		ms	D1 = 0	5,11
			3.5V	20		ms	D0 = 1	5,11
			5.5V	10		ms	D1 = 0	5,11
			3.5V	40		ms	D0 = 0	5,11
			5.5V	20		ms	D1 = 1	5,11
			3.5V	160		ms	D0 = 1	5,11
			5.5V	80		ms	D1 = 1	5,11

Notes:

1. Timing Reference uses 0.7 V_{CC} for a logic 1 and 0.2 V_{CC} for a logic 0.
2. Interrupt request via Port 3 (P31–P33)
3. Interrupt request via Port 3 (P30)
4. SMR-D5 = 1, POR STOP Mode Delay is on
5. Reg. WDTMR
6. The V_{CC} voltage spec. of 5.5V guarantees 5.0V ± 0.5V.
7. SMR D1 = 0
8. Maximum frequency for internal system clock is 4 MHz when using XTAL divide-by-one mode.
9. For RC and LC oscillator, and for oscillator driven by clock driver.
10. Standard Mode (not Low EMI output ports)
11. Using internal RC

PIN FUNCTIONS

EPROM Programming Mode

D7–D0 Data Bus. The data can be read from or written to external memory through the data bus.

A11–A0 Address Bus. During programming, the EPROM address is written to the address bus.

V_{CC} Power Supply. This pin must supply 5V during the EPROM read mode and 6V during other modes.

$\overline{CE}$ Chip Enable (active Low). This pin is active during EPROM Read Mode, Program Mode, and Program Verify Mode.

$\overline{OE}$ Output Enable (active Low). This pin drives the direction of the Data Bus. When this pin is Low, the Data Bus is output, when High, the Data Bus is input.

EPM EPROM Program Mode. This pin controls the different EPROM Program Mode by applying different voltages.

V_{PP} Program Voltage. This pin supplies the program voltage.

$\overline{PGM}$ Program Mode (active Low). When this pin is Low, the data is programmed to the EPROM through the Data Bus.

Application Precaution

The production test-mode environment may be enabled accidentally during normal operation if excessive noise surges above V_{CC} occur on pins XTAL1 and $\overline{RESET}$.

In addition, processor operation of Z8 OTP devices may be affected by excessive noise surges on the V_{PP}, $\overline{CE}$, $\overline{EPM}$, $\overline{OE}$ pins while the microcontroller is in Standard Mode.

Recommendations for dampening voltage surges in both test and OTP mode include the following:

- Using a clamping diode to V_{CC}
- Adding a capacitor to the affected pin

Standard Mode

XTAL Crystal 1 (time-based input). This pin connects a parallel-resonant crystal, ceramic resonator, LC, RC network, or external single-phase clock to the on-chip oscillator input.

XTAL2 Crystal 2 (time-based output). This pin connects a parallel-resonant crystal, ceramic resonator, LC, or RC network to the on-chip oscillator output.

R/$\overline{W}$ Read/Write (output, write Low). The R/$\overline{W}$ signal is Low when the CCP is writing to the external program or data memory (Z86E40 only).

$\overline{RESET}$ Reset (input, active Low). Reset will initialize the MCU. Reset is accomplished either through Power-On, Watch-Dog Timer reset, STOP-Mode Recovery, or external reset. During Power-On Reset and Watch-Dog Timer Reset, the internally generated reset drives the reset pin low for the POR time. Any devices driving the reset line must be open-drain in order to avoid damage from a possible conflict during reset conditions. Pull-up is provided internally. After the POR time, $\overline{RESET}$ is a Schmitt-triggered input.

To avoid asynchronous and noisy reset problems, the Z86E40 is equipped with a reset filter of four external clocks (4TpC). If the external reset signal is less than 4TpC in duration, no reset occurs. On the fifth clock after the reset is detected, an internal RST signal is latched and held for an internal register count of 18 external clocks, or for the duration of the external reset, whichever is longer. During the reset cycle, $\overline{DS}$ is held active Low while $\overline{AS}$ cycles at a rate of TpC/2. Program execution begins at location 000CH, 5–10 TpC cycles after $\overline{RESET}$ is released. For Power-On Reset, the reset output time is 5 ms. The Z86E40 does not reset WDTMR, SMR, P2M, and P3M registers on a STOP-Mode Recovery operation.

$\overline{ROMless}$ (input, active Low). This pin, when connected to GND, disables the internal ROM and forces the device to function as a Z86C90/C89 ROMless Z8. (Note that, when left unconnected or pulled High to V_{CC}, the device functions normally as a Z8 ROM version).

Note: When using in ROM Mode in High EMI (noisy) environment, the ROMless pins should be connected directly to V_{CC}.

Port 0 (P07–P00). Port 0 is an 8-bit, bidirectional, CMOS-compatible I/O port. These eight I/O lines can be configured under software control as a nibble I/O port, or as an address port for interfacing external memory. The input buffers are Schmitt-triggered and nibble programmed. Either nibble output that can be globally programmed as push-pull or open-drain. Low EMI output buffers can be globally programmed by the software. Port 0 can be placed under handshake control. In Handshake Mode, Port 3 lines P32 and P35 are used as handshake control lines. The handshake direction is determined by the configuration (input or output) assigned to Port 0's upper nibble. The lower nibble must have the same direction as the upper nibble.

For external memory references, Port 0 provides address bits A11–A8 (lower nibble) or A15–A8 (lower and upper nibble) depending on the required address space. If the address range requires 12 bits or less, the upper nibble of Port 0 can be programmed independently as I/O while the lower nibble is used for addressing. If one or both nibbles are needed for I/O operation, they must be configured by writing to the Port 0 mode register. In ROMless mode, after a hardware reset, Port 0 is configured as address lines A15–A8, and extended timing is set to accommodate slow memory access. The initialization routine can include reconfiguration to eliminate this extended timing mode. In ROM mode, Port 0 is defined as input after reset.

Port 0 can be set in the High-Impedance Mode if selected as an address output state, along with Port 1 and the control signals $\overline{AS}$, $\overline{DS}$, and R/$\overline{W}$ (Figure 18).

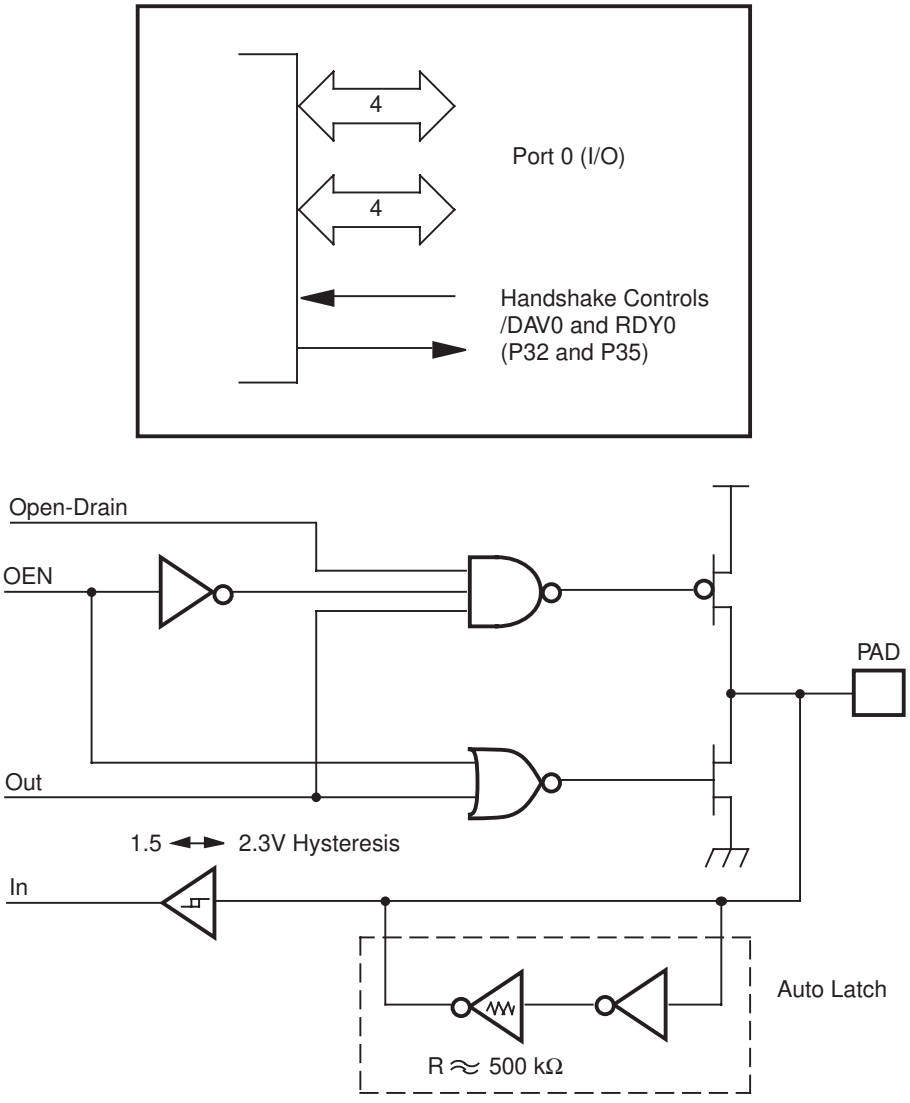

Figure 18. Port 0 Configuration